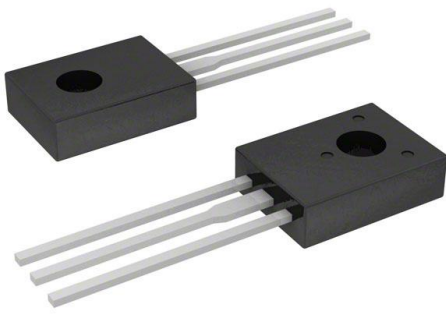


# MJE702STU Datasheet

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<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	MJE702STU-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	MJE702STU
Description	TRANS PNP DARL 80V 4A TO126-3
Detailed Description	Bipolar (BJT) Transistor PNP - Darlington 80 V 4 A 4 0 W Through Hole TO-126-3



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

MJE702STU

Series:

-

Transistor Type:

PNP - Darlington

Voltage - Collector Emitter Breakdown (Max):

80 V

Current - Collector Cutoff (Max):

100 $\mu$ A

Power - Max:

40 W

Operating Temperature:

150°C (TJ)

Package / Case:

TO-225AA, TO-126-3

Base Product Number:

MJE702

Manufacturer:

onsemi

Product Status:

Obsolete

Current - Collector (Ic) (Max):

4 A

Vce Saturation (Max) @ Ib, Ic:

2.5V @ 30mA, 1.5A

DC Current Gain (hFE) (Min) @ Ic, Vce:

750 @ 1.5A, 3V

Frequency - Transition:

-

Mounting Type:

Through Hole

Supplier Device Package:

TO-126-3

## Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

REACH Status:

REACH Unaffected

HTSUS:

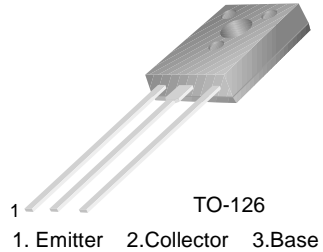
8541.29.0095



# MJE700/701/702/703

## Monolithic Construction With Built-in Base-Emitter Resistors

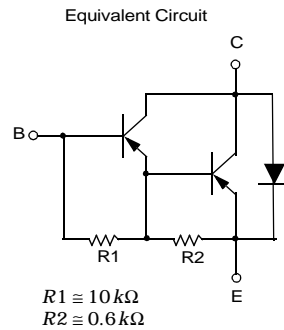
- High DC Current Gain :  $h_{FE} = 750$  (Min.) @  $I_C = -1.5$  and  $-2.0A$  DC
- Complement to MJE800/801/802/803



## PNP Epitaxial Silicon Darlington Transistor

### Absolute Maximum Ratings $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector- Base Voltage : MJE700/701	- 60	V
	: MJE702/703	- 80	V
$V_{CEO}$	Collector-Emitter Voltage : MJE700/701	- 60	V
	: MJE702/703	- 80	V
$V_{EBO}$	Emitter- Base Voltage	- 5	V
$I_C$	Collector Current	- 4	A
$I_B$	Base Current	- 0.1	A
$P_C$	Collector Dissipation ( $T_C = 25^\circ C$ )	40	W
$T_J$	Junction Temperature	150	$^\circ C$
$T_{STG}$	Storage Temperature	- 55 ~ 150	$^\circ C$



### Electrical Characteristics $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$BV_{CEO}$	Collector-Emitter Breakdown Voltage : MJE700/701	$I_C = -10\text{mA}, I_B = 0$	-60		V
	: MJE702/703		-80		V
$I_{CEO}$	Collector Cut-off Current : MJE700/701	$V_{CE} = -60\text{V}, I_B = 0$		-100	$\mu\text{A}$
	: MJE702/703	$V_{CE} = -80\text{V}, I_B = 0$		-100	$\mu\text{A}$
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = \text{Rated } BV_{CEO}, I_E = 0$		-100	$\mu\text{A}$
		$V_{CB} = \text{Rated } BV_{CEO}, I_E = 0$ $T_C = 100^\circ C$		-500	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{BE} = -5\text{V}, I_C = 0$		-2	mA
$h_{FE}$	DC Current Gain	$V_{CE} = -3\text{V}, I_C = -1.5\text{A}$	750		
		$V_{CE} = -3\text{V}, I_C = -2\text{A}$	750		
		$V_{CE} = -3\text{V}, I_C = -4\text{A}$	100		
		: ALL DEVICES			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -1.5\text{A}, I_B = -30\text{mA}$		-2.5	V
		$I_C = -2\text{A}, I_B = -40\text{mA}$		-2.8	V
		$I_C = -4\text{A}, I_B = -40\text{mA}$		-3	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE} = -3\text{V}, I_C = -1.5\text{A}$		-1.2	V
		$V_{CE} = -3\text{V}, I_C = -2\text{A}$		-2.5	V
		$V_{CE} = -3\text{V}, I_C = -4\text{A}$		-3	V
		: ALL DEVICES			

# Typical Characteristics

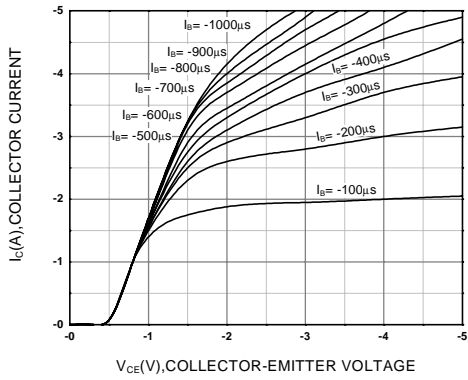


Figure 1. Static Characteristic

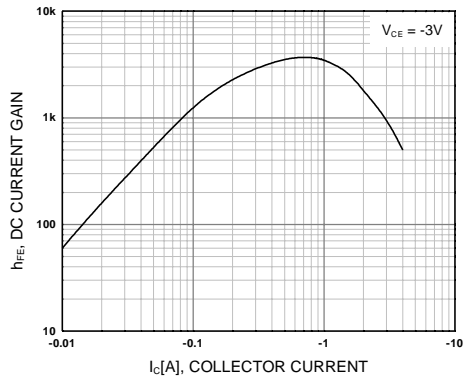


Figure 2. DC current Gain

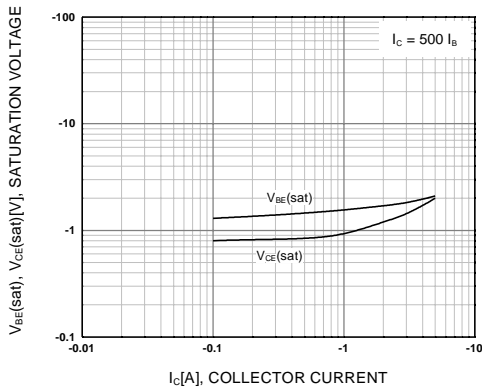


Figure 3. Collector-Emitter Saturation Voltage  
Base-Emitter Saturation Voltage

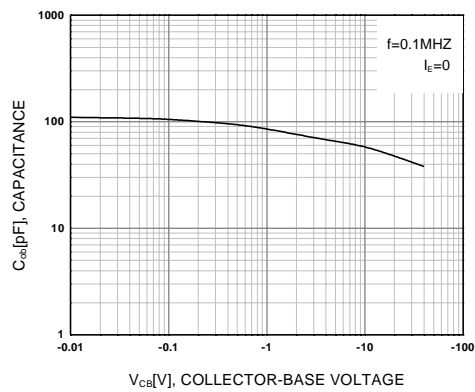


Figure 4. Collector Output Capacitance

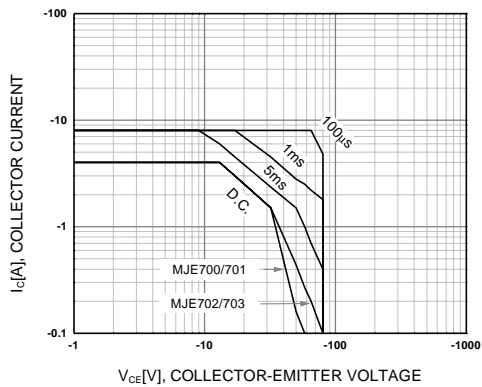


Figure 5. Safe Operating Area

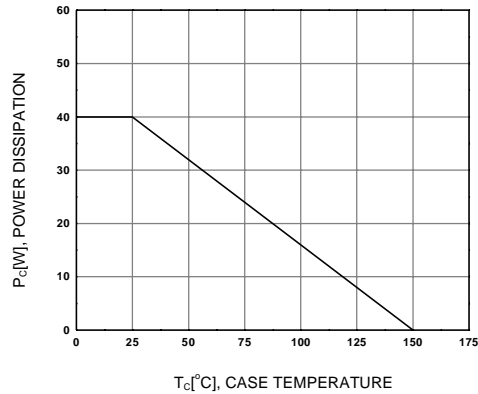
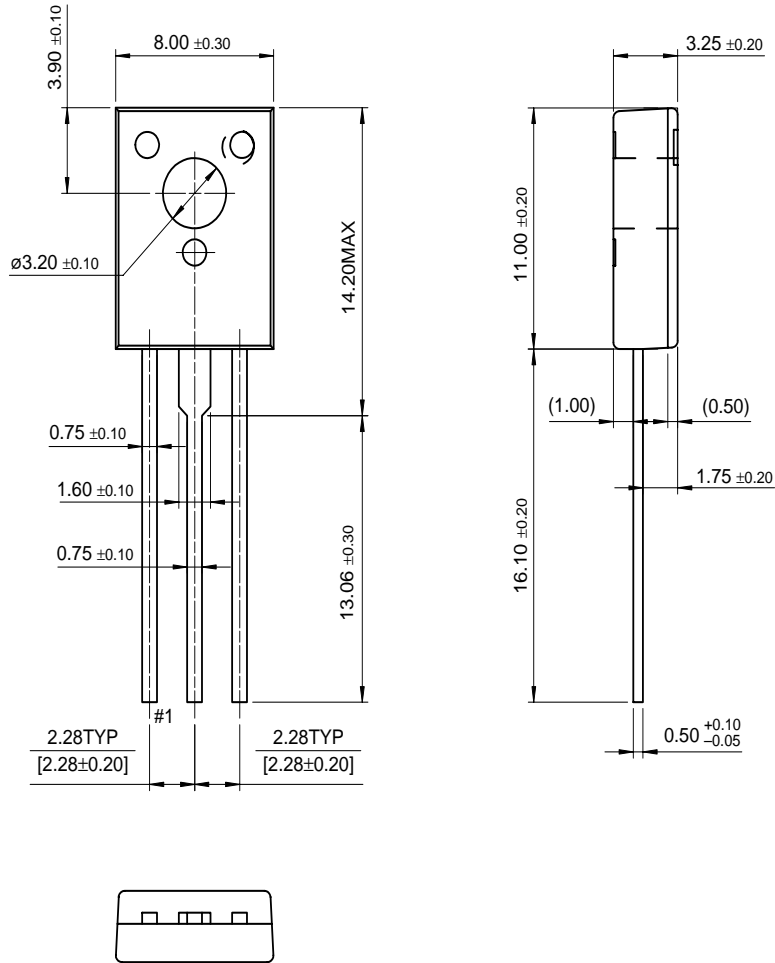


Figure 6. Power Derating

# Package Dimensions

## TO-126



Dimensions in Millimeters

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CROSSVOLT™	HiSeC™	QT Optoelectronics™	UHC™
DOME™	ISOPLANAR™	Quiet Series™	
E <sup>2</sup> CMOS™	MICROWIRE™	LILENT SWITCHER®	
EnSigna™	OPTOLOGIC™	SMART START™	
FACT™	OPTOPLANAR™	SuperSOT™-3	
FACT Quiet Series™	PACMAN™	SuperSOT™-6	
FAST®	POP™	SuperSOT™-8	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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